

**FEATURES**

- Schottky barrier rectifier
- Guardring protection
- Low forward voltage
- Reverse energy tested
- High current capability
- Extremely low thermal resistance

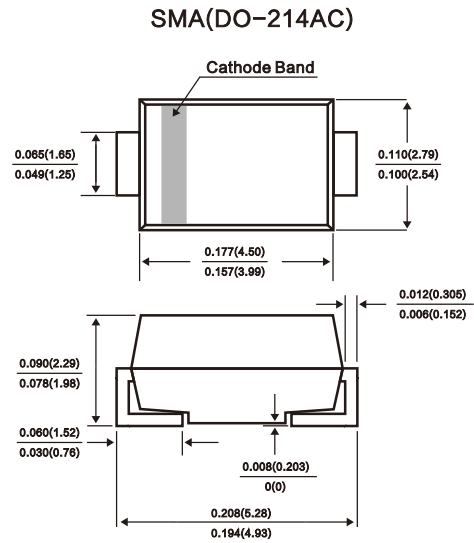
**Mechanical Data**

Case: SMA molded plastic body

Polarity: Color band denotes cathode end

Mounting position: ANY

Weight: 0.002 ounces, 0.064 gram



Dimensions in inches and (millimeters)

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	SS12	SS13	SS14	SS15	SS16	SS18	SS110	SS115	SS120	UNITS	
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	80	100	150	200	VOLTS	
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	56	70	105	140	VOLTS	
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	80	100	150	200	VOLTS	
Maximum average forward rectified current at $T_L$ (see fig.1)	$I_{(AV)}$	1.0									Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	30.0									Amps	
Maximum instantaneous forward voltage at 1.0A	$V_F$	0.45	0.55	0.70	0.85			0.95			Volts	
Maximum DC reverse current at rated DC blocking voltage	$I_R$	0.5						0.2				mA
		10.0			5.0		2.0					
Typical junction capacitance (NOTE 1)	$C_J$	110			90						pF	
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	88.0									°C/W	
Operating junction temperature range	$T_J$	-50 to +125					-50 to +150				°C	
Storage temperature range	$T_{STG}$	-50 to +150									°C	

**Note:**1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

FIG.1 – FORWARD DERATING CURVE

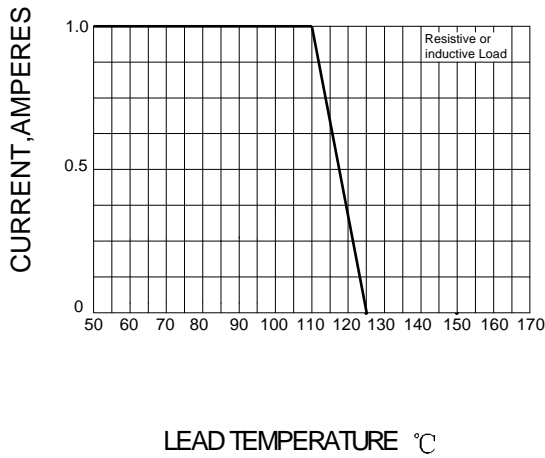


FIG.2– PEAK FORWARD SURGE CURRENT

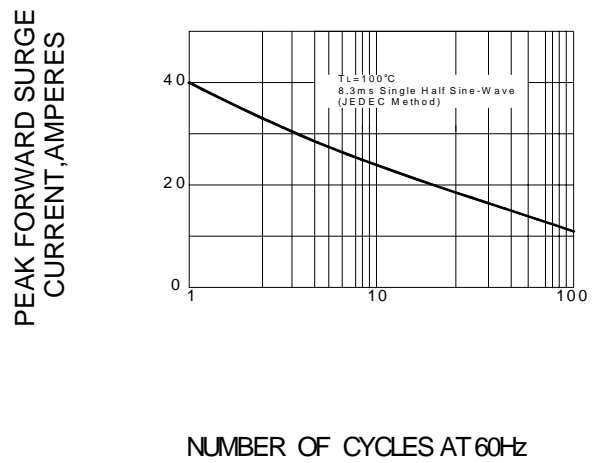


FIG.3 – TYPICAL FORWARD CHARACTERISTICS

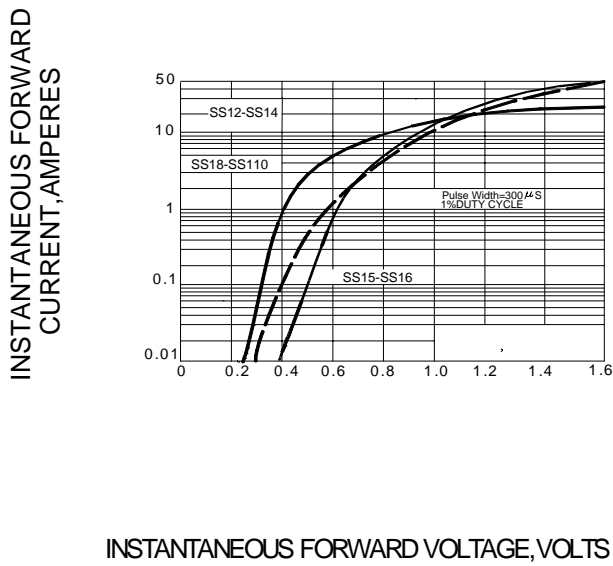
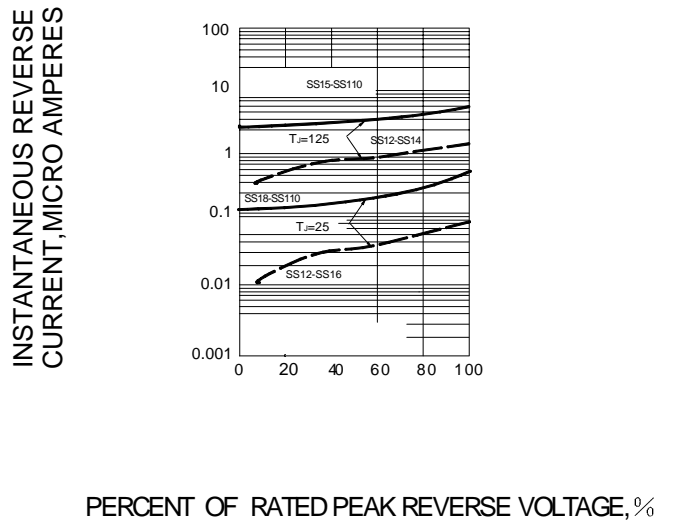


FIG.4 – TYPICAL REVERSE CHARACTERISTICS



单击下面可查看定价，库存，交付和生命周期等信息

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